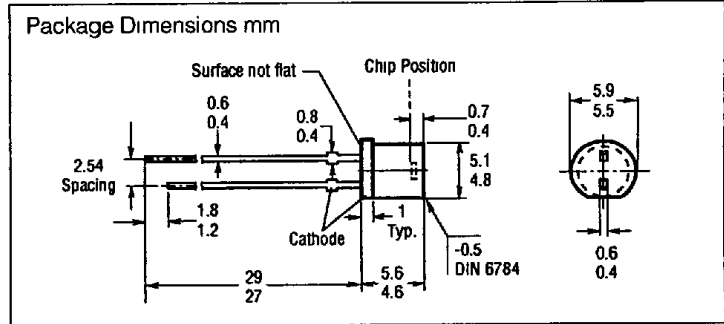
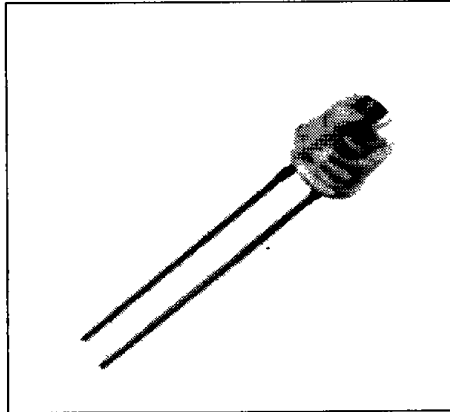


**SIEMENS**

T-41-51  
**SFH 263**  
 WITH FILTER **SFH 263F**  
**SILICON PHOTODIODE**  
**VERY LOW DARK CURRENT**



**FEATURES**

- Package: 5-mm LED Package, Flat Lens, Clear Epoxy Resin, Solder Tabs, Lead Spacing 2.54 mm (1/16")
- Cathode Marking: Short Solder Tab
- High Reliability
- No Testable Degradation
- Low Noise
- High Open-Circuit Voltage During Element Operation
- Detector for Low Illuminance
- Short Switching Time
- High Photosensitivity
- Wide Temperature Range
- Suitable for the Visible as well as the Infrared Range
- Daylight-Rejection Filter (SFH 263F)
- Same Package as Phototransistors SFH 317, SFH 317F, IRED SFH 485P, Photodiodes SFH 217, SFH 217F.

**DESCRIPTION**

The SFH 263 is a silicon photodiode fabricated in planar technology. The N-Si material used results in a positive front and negative back contact. These photo-detectors are suitable for diode operation (with reverse voltage) as well as for element operation.

Applications include exposure meters, automatic exposure timers, industrial electronics, "measuring and controlling".

**Maximum Ratings**

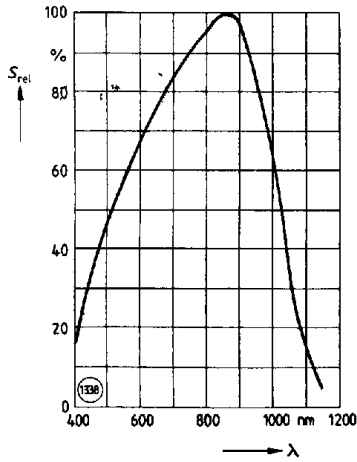
Operating and Storage Temperature Range ( $T_{op}$ )( $T_{stg}$ ) . . . . . -40°C to +80°C  
 Soldering Temperature (2 mm distance from case, t = 3 sec.) ( $T_s$ ) . . . . . 230°C  
 Reverse Voltage ( $V_R$ ) . . . . . 7 V  
 Total Power Dissipation ( $P_{tot}$ ) ( $T_A=25^\circ\text{C}$ ) . . . . . 100 mW

**Characteristics ( $T_A=25^\circ\text{C}$ )**

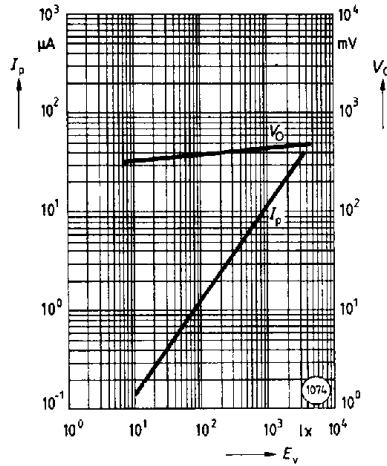
Parameter	Symbol	SFH263	SFH363F	Unit
Photosensitivity ( $V_R=5\text{ V}$ , standard light A, $T=2856\text{ K}$ , $\lambda=950\text{ nm}$ , $E_E=0.5\text{ mW/cm}^2$ )	S	10 ( $\geq 8$ )	2.5 ( $\geq 2$ )	nA/lx
Wavelength of Maximum Sensitivity	$\lambda_{smax}$	850	900	nm
Spectral Range of Photosensitivity (S = 10% of $S_{max}$ )	$\lambda$	350 - 1100	730 - 1100	nm
Radiant Sensitive Area	A	0.97		mm <sup>2</sup>
Dimensions of Radiant Sensitive Area	L x B	0.985 x 0.985		mm
Distance Chip Surface to Case Surface	H	0.4 - 0.7		mm
Half Angle	$\phi$	$\pm 60$		Deg
Dark Current ( $V_R=1\text{ V}$ )	$I_{s1}$	5 ( $\leq 20$ )		pA
Spectral Sensitivity ( $\lambda=850\text{ nm}$ )	$S_\lambda$	0.50		A/W
Zero Crossover ( $E_E=0$ , $T_A=25^\circ\text{C}$ )	$S_0$	$\geq 0.5$		mW/pA
Quantum Yield ( $\lambda=850\text{ nm}$ )	$\eta$	0.73		electrons/ photon
Open-Circuit Voltage ( $E_v=1000\text{ lx}$ , standard light A, $T=2856\text{ K}$ , $\lambda=950\text{ nm}$ , $E_E=0.5\text{ mW/cm}^2$ )	$V_0$	450 ( $\geq 380$ )	400 ( $\geq 350$ )	mV
Short-Circuit Current ( $E_v=1000\text{ lx}$ , standard light A, $T=2856\text{ K}$ , $\lambda=950\text{ nm}$ , $E_E=0.5\text{ mW/cm}^2$ )	$I_{s1}$	10 ( $\geq 8$ )	2.5 ( $\geq 2$ )	$\mu\text{A}$
Rise and Fall Time of Photocurrent (from 10% to 90%, or from 90% to 10% of final value) ( $R_L=1\text{ k}\Omega$ , $V_R=5\text{ V}$ , $\lambda=830\text{ nm}$ , $I_p=10\text{ }\mu\text{A}$ )	$t_r, t_f$	1.3		$\mu\text{s}$
Forward Voltage ( $I_f=100\text{ mA}$ , $E=0$ , $T_A=25^\circ\text{C}$ )	$V_F$	1.3		V
Capacitance ( $V_R=0\text{ V}$ , $f=1\text{ MHz}$ , $E_v=0\text{ lx}$ )	$C_0$	100		pF
Temperature Coefficient of $V_0$ ( $\lambda=950\text{ nm}$ )	$TC_{V_0}$	-2.6	-2.6	mV/K
Temperature Coefficient of $I_{s1}$ ( $\lambda=950\text{ nm}$ )	$TC_{I_{s1}}$	0.16	0.16	%/K
Noise Equivalent Power ( $V_R=1\text{ V}$ )	NEP	$2.5 \times 10^{-15}$		W/ $\sqrt{\text{Hz}}$
Detection Limit ( $V_R=1\text{ V}$ )	D	$3.9 \times 10^{13}$		$\text{cm} \cdot \sqrt{\text{Hz/W}}$

T-41-51

Relative spectral sensitivity versus wavelength



Photocurrent and open-circuit voltage versus illuminance



Directional characteristic  
Relative spectral sensitivity versus half angle

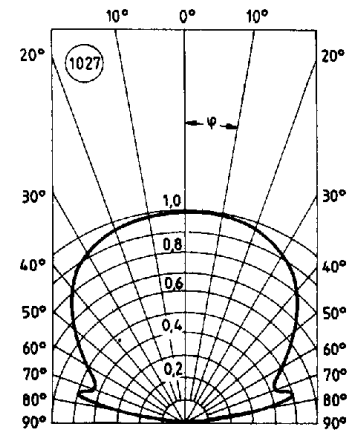
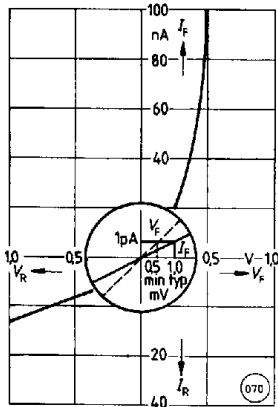
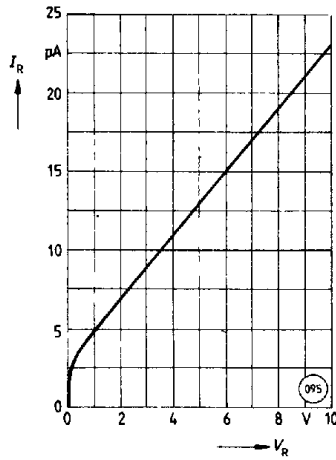


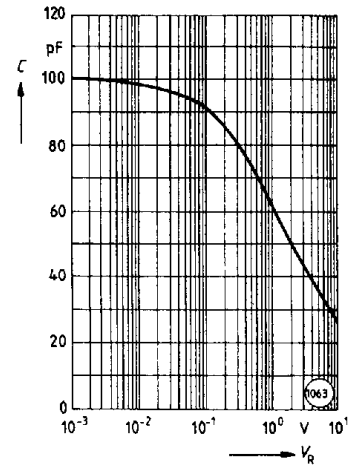
Diagram of zero crossover  $S_o = \frac{V_F}{I_F}$



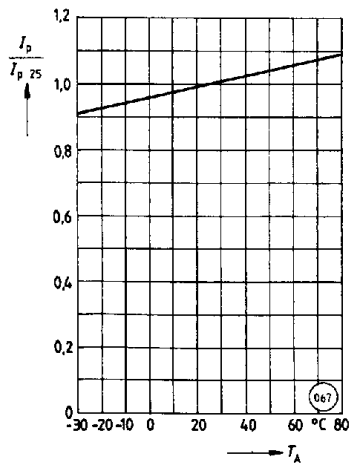
Dark current versus reverse voltage  
( $T_A=25^\circ\text{C}$ ,  $E_v=0$ )



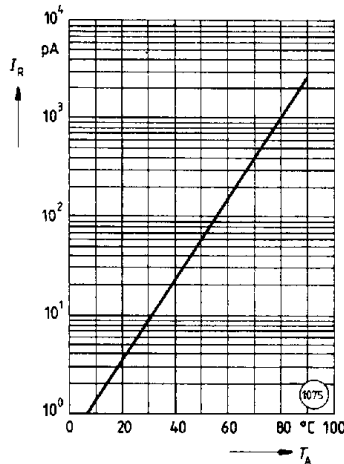
Capacitance versus reverse voltage  
( $E=0$ ,  $f=1\text{ MHz}$ )



Photocurrent versus ambient temperature



Dark current versus ambient temperature  
( $V_R=1\text{ V}$ ,  $E_v=0$ )



Photodiodes